

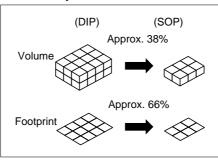


GU (General Use) Type SOP Series [2-Channel (Form A Form B) Type]

FEATURES

1. 2 channels in super miniature design

The device comes in a super-miniature SO package measuring (W) $4.4 \times (L) 9.37 \times (H) 2.1 \text{ mm} (W) .173 \times (L) .369 \times (H) .083$ inch —approx. 38% of the volume and 66% of the footprint size of DIP type PhotoMOS Relays.



2. Tape and reel

The device comes standard in a tape and reel (1,000 pcs./reel) to facilitate automatic insertion machines.

Applicable for 1 Form A 1 Form B use as well as two independent 1 Form A and 1 Form B use

PhotoMOS

RELAYS

Controls low-level analog signals PhotoMOS relays feature extremely low closed-circuit offset voltage to enable control of low-level analog signals without distortion

5. Low-level off state leakage current

TYPICAL APPLICATIONS

- Telephones
- Measuring instruments
- Computer
- Industrial robots
- High-speed inspection machines.

TYPES

1. AC/DC type

Output rating*		Part	Deaking quantity in tang and real	
Load voltage	Load current	Picked from the 1/2/3/4-pin side	Picked from the 5/6/7/8-pin side	Packing quantity in tape and reel
350 V	100 mA	AQW610SX	AQW610SZ	1,000 pcs.

*Indicate the peak AC and DC values.

Notes: (1) Tape package is the standard packing style. Also available in tube. (Part No. suffix "X" or "Z" is not needed when ordering; Tube: 50 pcs.; Case: 1,000 pcs.)

(2) For space reasons, the package type indicator "X" and "Z" are omitted from the seal.

RATING

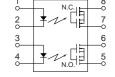
1. AC/DC type

1. Absolute maximum ratings (Ambient temperature : 25°C 77°F)

	Item	Symbol	AQW610S	Remarks
Input	LED forward current	lF	50 mA	
	LED reverse voltage	VR	3 V	
	Peak forward current	I FP	1 A	f = 100 Hz, Duty factor = 0.1%
	Power dissipation	Pin	75 mW	
Output	Load voltage (peak AC)	VL	350 V	
	Continuous load current	IL.	0.1 A (0.13 A)	Peak AC, DC (): in case of using only 1a or 1b, 1 channel
	Peak load current	Ipeak	0.3 A	100 ms (1 shot), V∟ = DC
	Power dissipation	Pout	600 mW	
Total power dissipation		Ρτ	650 mW	
I/O isolation voltage		Viso	1,500 V AC	
Temperature limits	Operating	Topr	-40°C to +85°C -40°F to +185°F	Non-condensing at low temperatures
	Storage	Tstg	-40°C to +100°C -40°F to +212°F	



mm inch

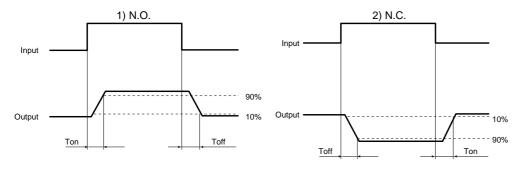


AQW610S

2. Electrical characteris	stics (Ambient temperature :	25°C 77°F) Symbol		1
Item				AQW610S	Condition
	LED operate current	Typical	- IFon	0.9 mA	l∟ = Max.
		Maximum		3 mA	
Innut	LED reverse current	Minimum	- I _{Foff}	0.4 mA	l∟ = Max.
Input		Typical		0.8 mA	
		Typical	VF	1.14 V (1.25 V at I⊧ = 50 mA)	l⊧ = 5 mA
	LED dropout voltage	Maximum	VF	1.5 V	
	On resistance	Typical		18 Ω	$ \begin{array}{l} I_{\text{F}}=5 \text{ mA (N.O.)} \ I_{\text{F}}=0 \text{ mA (N.C.)} \\ I_{\text{L}}=Max. \\ Within 1 \text{ s on time} \end{array} $
Output		Maximum	Ron	25 Ω	
	Off state leakage current	Maximum	lleak	1 μΑ	$ I_{F} = 0 \text{ mA (N.O.)} I_{F} = 5 \text{ mA (N.C.)} $ $ V_{L} = Max. $
	Operate time*	Typical	- T _{on}	0.28 ms (N.O.), 0.52 ms (N.C.)	$I_F = 0 \text{ mA} \rightarrow 5 \text{ mA}$ $I_L = Max.$
	Operate time*	Maximum		1.0 ms	
	Describe	Typical	Toff	0.04 ms (N.O.), 0.23 ms (N.C.)	$I_F = 5 \text{ mA} \rightarrow 0 \text{ mA}$ $I_L = Max.$
Transfer characteristics	Reverse time*	Maximum		1.0 ms	
		Typical	Ciso	0.8 pF	f = 1 MHz Vв = 0
	I/O capacitance	Maximum		1.5 pF	
	Initial I/O isolation resistance	Minimum	Riso	1,000 MΩ	500 V DC

Note: Recommendable LED forward current $I_F = 5 \text{ mA.}$

*Operate/Reverse time

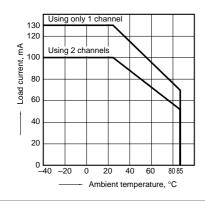


For type of connection, see page 32.

REFERENCE DATA

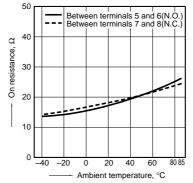
1. Load current vs. ambient temperature characteristics

Allowable ambient temperature: –40°C to +85°C -40°F to +185°F



2. On resistance vs. ambient temperature characteristics

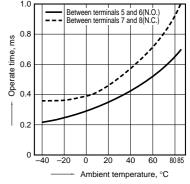
Measured portion: between terminals 5 and 6, 7 and 8; LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



3. Opearte time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)

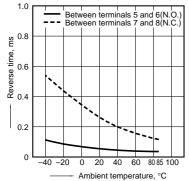
1.0



AQW610S

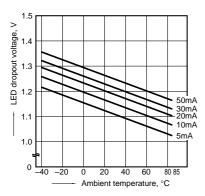
4. Reverse time vs. ambient temperature characteristics

LED current: 5 mA; Load voltage: Max. (DC); Continuous load current: Max. (DC)



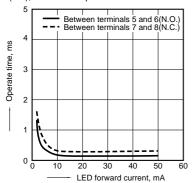
7. LED dropout voltage vs. ambient temperature characteristics

LED current: 5 to 50 mA



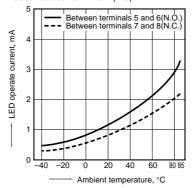
10. LED forward current vs. operate time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: 25°C 77°F



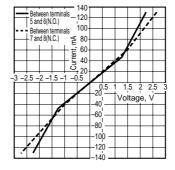
5. LED operate current vs. ambient temperature characteristics

Load voltage: Max. (DC); Continuous load current: Max. (DC)

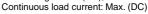


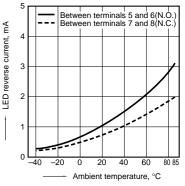
8. Voltage vs. current characteristics of output at MOS portion

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



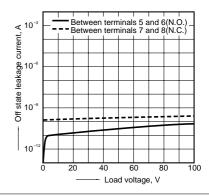
6. LED Reverse current vs. ambient temperature characteristics Load voltage: Max. (DC);





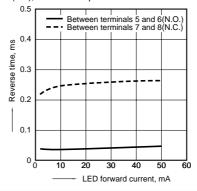
9. Off state leakage current

Measured portion: between terminals 5 and 6, 7 and 8; Ambient temperature: 25°C 77°F



11. LED forward current vs. reverse time characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Load voltage: Max. (DC); Continuous load current: Max. (DC); Ambient temperature: $25^{\circ}C$ $77^{\circ}F$



12. Applied voltage vs. output capacitance characteristics

Measured portion: between terminals 5 and 6, 7 and 8; Frequency: 1 MHz;

